AMENDMENTS TO THE SPECIFICATION AND ABSTRACT

In the specification, page 1, please add the following heading under the title as follows:

BACKGROUND OF THE INVENTION

In the specification, page 1, line 6, please amend the sub-heading as follows:

1. TECHNICAL FIELDFIELD OF THE INVENTION

In the specification, page 1, line 10, please amend the sub-heading as follows:

2. BACKGROUND ARTDESCRIPTION OF THE RELATED ART

In the specification, page 1, lines 11-15, please amend the paragraph as follows:

In a communication device such as a portable phone, a surface acoustic wave filter is used for extracting only <u>a</u> required frequency. Such a surface acoustic wave filter is required to have various characteristics corresponding to the communication device, such as a filter characteristic of low loss and broad band.

In the specification, page 1, lines 29-30 to page 2, lines 1-4, please amend the paragraph as follows:

The frequency of the communication device, such as the portable phone employing such a surface acoustic wave filter, has increased, and a surface acoustic wave filter responsive to the increase is required. For responding to the increase in frequency, technology of decreasing the propagation loss using a 38° - 46° Y cut X propagation lithium tantalate (LiTaO₃) substrate as

the piezoelectric substrate has been developed.

In the specification, page 3, in the title preceding lines 8-20, please amend as follows:

BRIEF SUMMARY OF THE INVENTION

In the specification, page 7, in the title preceding lines 12-16, please amend as follows:

DETAILED DESCRIPTION OF THE INVENTION PREFERRED EMBODIMENTS

In the specification, page 14, lines 26-30 to page 15, lines 1 and 2, please amend the paragraph as follows:

Both of two series resonators have a gradation region in the present embodiment.; however, However, all series resonators are not required to have a gradation region. However, it is preferable to form gradation regions in all series resonators, because the ripple can be further reduced. When there are a plurality of series resonators and each resonator has a different number of electrode finger pairs in each IDT, it is preferable to form a gradation region especially in the resonator having a small number of IDT pairs.

In the specification, page 16, in the title preceding lines 15-18, please amend as follows:

INDUSTRIAL APPLICABILITY